

Docket No.: 20433-00601-US1  
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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In re Patent Application of:  
Katsuki Hazama

Application No.: TBA  
(Div. of 10/118,039)

Art Unit: 2824

Filed: Concurrently Herewith

Examiner: Not Yet Assigned

For: SEMICONDUCTOR DEVICE INCLUDING  
TRANSISTOR WITH COMPOSITE GATE  
STRUCTURE AND TRANSISTOR WITH  
SINGLE GATE STRUCTURE, AND METHOD  
FOR MANUFACTURING THE SAME

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**FIRST PRELIMINARY AMENDMENT**

MS Non-Fee Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

**INTRODUCTORY COMMENTS**

Prior to examination on the merits, please amend the above-identified U.S. patent application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 3 of this paper.

**Remarks/Arguments** begin on page 7 of this paper.